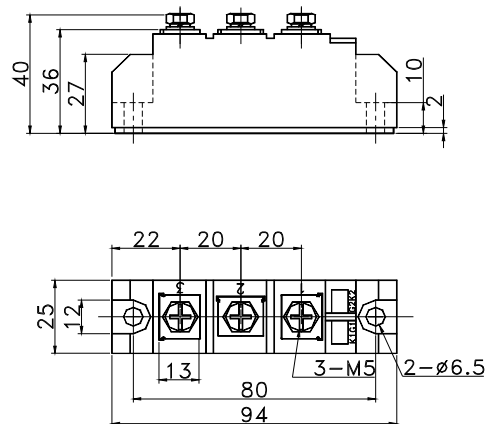
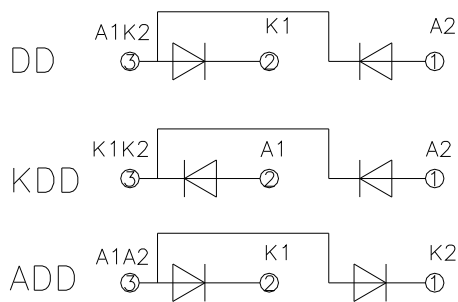


DD110 ADD110 KDD110

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _C =100°C	150			110	A
I _{F(RMS)}	RMS forward current	Single side cooled, T _C =100°C	150			173	A
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RSM} = V _{DRM} &V _{RRM} +200V	150	600		1800	V
I _{RRM}	Repetitive peak current	at V _{RRM}	150			8	mA
I _{FSM}	Surge forward current	10ms half sine wave	150			2.60	KA
I ² t	I ² T for fusing coordination	V _R =0.6V _{RRM}				34.4	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.80	V
r _F	Forward slop resistance					1.74	mΩ
V _{FM}	Peak forward voltage	I _{FM} =330A	25			1.45	V
R _{th(j-c)}	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.350	°C /W
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1min, I _{iso} :1mA(max)		2500			V
F _m	Terminal connection torque(M5)				2.0		N·m
	Mounting torque(M6)				3.0		N·m
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				160		g
Outline	202F3						

OUTLINE DRAWING & CIRCUIT DIAGRAM



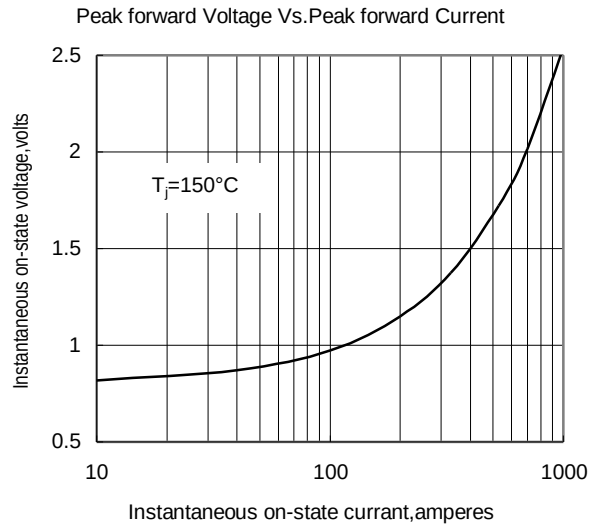


Fig.1

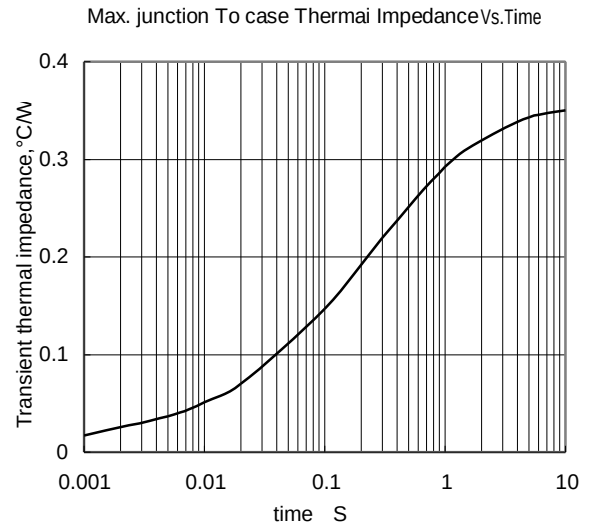


Fig.2

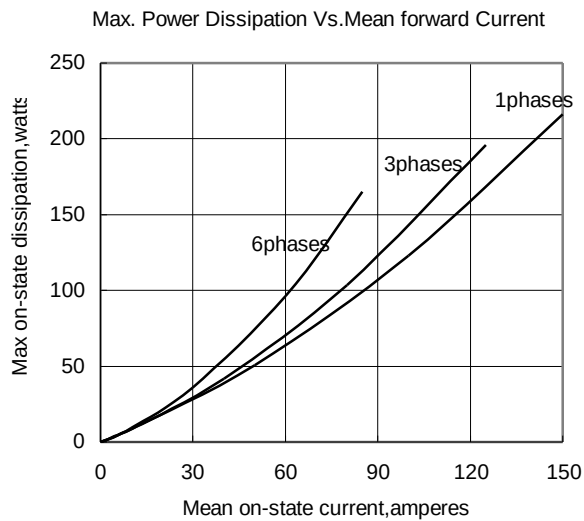


Fig.3

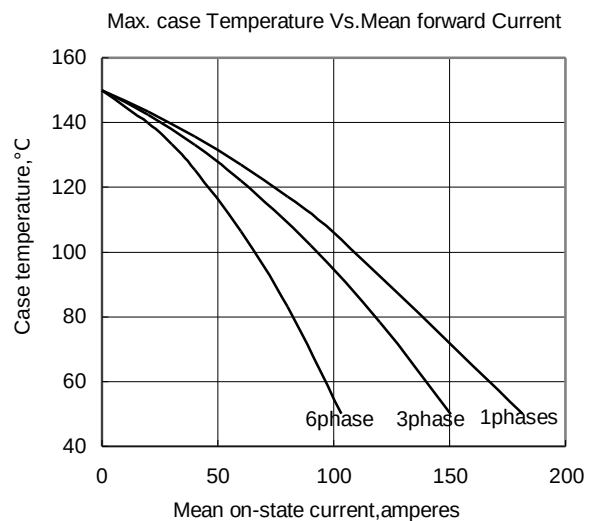


Fig.4

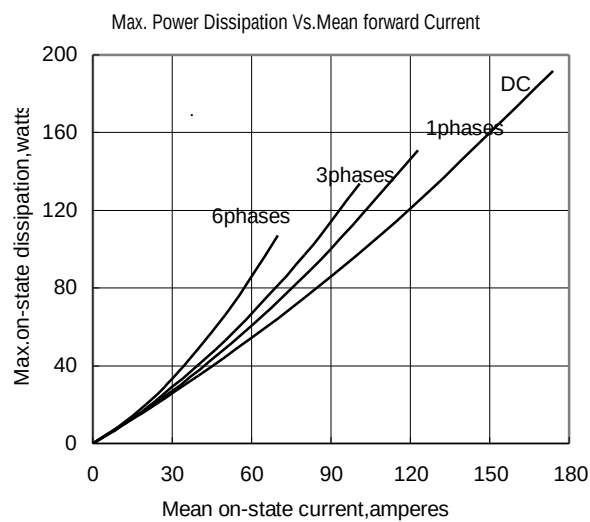


Fig.5

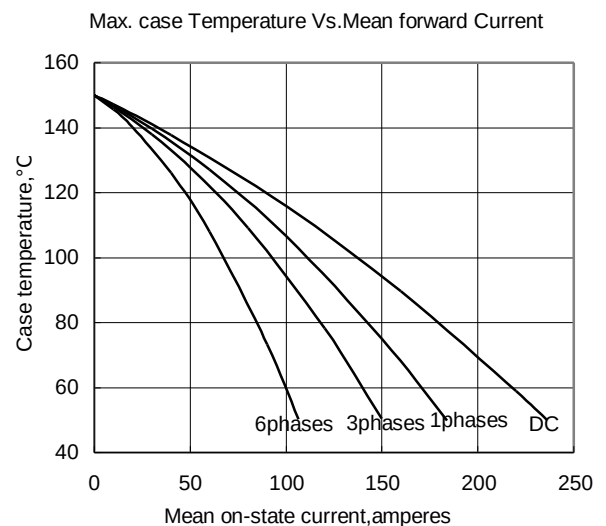


Fig.6